

● FEATURES

Power dissipation

 P_D: 150 mW (T_{amb}=25°C)

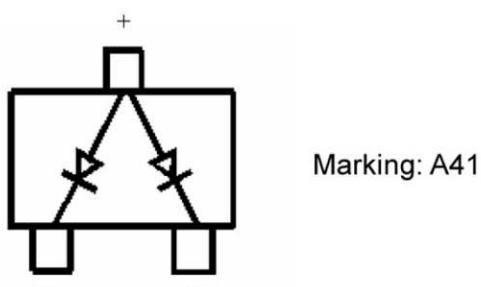
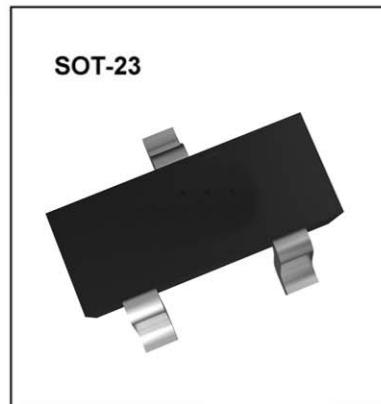
Forward Current

 I_F: 300 m A

Reverse Voltage

 V_R: 50 V

Operating and storage junction temperature range

 T_J, T_{stg}: -55°C to +150°C

● ELECTRICAL CHARACTERISTICS (T_{amb}=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Reverse breakdown voltage	V _(BR)	I _R = 100μA	50		V
Reverse voltage leakage current	I _R	V _R =50V		0.1	μA
Forward voltage	V _F	I _F =10mA I _F =50mA I _F =100mA		0.9 1 1.2	V
Diode capacitance	C _D	V _R =0V, f=1MHz		4	pF
Reverse recovery time	t _{rr}	I _F =I _R =10mA, I _{RR} =0.1×I _R		4	nS

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